查询MAX3243CDB供应商

捷多邦,专业PCB打样工厂,24小时加急出货 MAX3243 3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER

- Single-Chip and Single-Supply Interface for IBM[™] PC/AT[™] Serial Port
- Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU v.28 Standards
- Operates With 3-V to 5.5-V V_{CC} Supply
- Always-Active Noninverting Receiver Output (ROUT2B)
- Operates up to 250 kbit/s
- Low Standby Current ... 1 μA Typical
- External Capacitors . . . 4 × 0.1 μF
- Accepts 5-V Logic Input With 3.3-V Supply
- Designed to Be Interchangeable With Maxim MAX3243
- Serial-Mouse Driveability
- RS-232 Bus-Pin ESD Protection Exceeds ±15-kV Using Human-Body Model (HBM)
 - Applications
 Battery-Powered Systems, PDAs, Notebooks, Laptops, Palmtop PCs, and Hand-Held Equipment
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages

description

The MAX3243 device consists of three line drivers, five line receivers, and a dual charge-pump circuit with \pm 15-kV ESD protection pin-to-pin (serial-port connection pins, including GND). The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. This combination of drivers and receivers matches that needed for the typical serial port used in an IBM PC/AT, or compatible. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. In addition, the device includes an always-active noninverting output (ROUT2B), which allows applications using the ring indicator to transmit data while the device is powered down. The device operates at data signaling rates up to 250 kbit/s and a maximum of 30-V/ μ s driver output slew rate.

Flexible control options for power management are available when the serial port is inactive. The auto-powerdown feature functions when FORCEON is low and FORCEOFF is high. During this mode of operation, if the device does not sense a valid RS-232 signal, the driver outputs are disabled. If FORCEOFF is set low, both drivers and receivers (except ROUT2B) are shut off, and the supply current is reduced to 1 µA. Disconnecting the serial port or turning off the peripheral drivers causes the auto-powerdown condition to occur.



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DB, DW,	OR PW		
, ,	1 2 3 4 5 6 7 8 9 10 11 12		
DIN1		15	ROUT5

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description (continued)

Auto-powerdown can be disabled when FORCEON and FORCEOFF are high, and should be done when driving a serial mouse. With auto-powerdown enabled, the device is activated automatically when a valid signal is applied to any receiver input. The INVALID output is used to notify the user if an RS-232 signal is present at any receiver input. INVALID is high (valid data) if any receiver input voltage is greater than 2.7 V or less than -2.7 V or has been between -0.3 V and 0.3 V for less than $30 \ \mu s$. INVALID is low (invalid data) if all receiver input voltages are between -0.3 V and 0.3 V for more than $30 \ \mu s$. Refer to Figure 5 for receiver input levels.

The MAX3243C is characterized for operation from 0°C to 70°C. The MAX3243I is characterized for operation from -40°C to 85°C.

AVAILABLE OPTIONS PACKAGED DEVICES SHRINK THIN SHRINK SMALL OUTLINE TA SMALL OUTLINE SMALL OUTLINE (DW) (DB) (PW) 0°C to 70°C MAX3243CDB MAX3243CDW MAX3243CPW -40°C to 85°C MAX3243IDB MAX3243IDW MAX3243IPW

The DB, DW, and PW packages are available taped and reeled. Add the suffix R to device type (e.g., MAX3243CDBR).

Function Tables

EACH DRIVER

		INPUTS		OUTPUT	
DIN	FORCEON	FORCEOFF	VALID RIN RS-232 LEVEL	DOUT	DRIVER STATUS
Х	Х	L	Х	Z	Powered off
L	Н	Н	Х	Н	Normal operation with
Н	Н	Н	Х	L	auto-powerdown disabled
L	L	Н	Yes	Н	Normal operation with
Н	L	Н	Yes	L	auto-powerdown enabled
L	L	Н	No	Z	Powered off by
Н	L	Н	No	Z	auto-powerdown feature

H = high level, L = low level, X = irrelevant, Z = high impedance

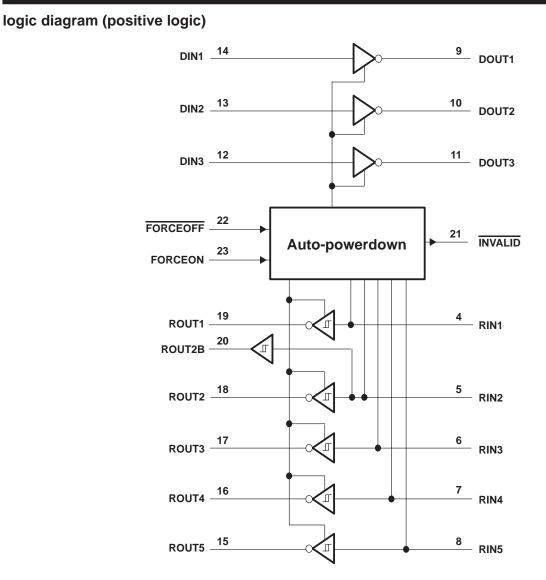
EACH RECEIVER

		INPUTS	-	OUTP	UTS	
RIN2	RIN1, RIN3–RIN5	FORCEOFF	VALID RIN RS-232 LEVEL	ROUT2B	ROUT	RECEIVER STATUS
L	Х	L	Х	L	Z	Powered off while
н	Х	L	Х	Н	Z	ROUT2B is active
L	L	Н	Yes	L	Н	
L	Н	Н	Yes	L	L	Normal operation with
н	L	н	Yes	н	Н	auto-powerdown
н	Н	Н	Yes	н	L	disabled/enabled
Open	Open	Н	No	L	Н	

H = high level, L = low level, X = irrelevant, Z = high impedance (off), Open = input disconnected or connected driver off



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range (/ (ase Note 1)	
Supply voltage range, V _{CC} (see Note 1)	
Positive output supply voltage range, V+ (see Note 1)	–0.3 V to 7 V
Negative output supply voltage range, V– (see Note 1)	0.3 V to –7 V
Supply voltage difference, V+ – V– (see Note 1)	13 V
Input voltage range, VI: Driver (FORCEOFF, FORCEON)	–0.3 V to 6 V
Receiver	
Output voltage range, V _O : Driver	–13.2 V to 13.2 V
Receiver (INVALID)	$\dots -0.3$ V to V _{CC} + 0.3 V
Package thermal impedance, θ_{JA} (see Note 2): DB package	
DW package	46°C/W
PW package	62°C/W
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C
Storage temperature range, T _{stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltages are with respect to network GND.

2. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 3 and Figure 6)

				MIN	NOM	MAX	UNIT
	Supply voltage		V _{CC} = 3.3 V	3	3.3	3.6	V
	Supply voltage		$V_{CC} = 5 V$	4.5	5	5.5	v
V	Driver and control high-level input voltage			2			V
VIH	Driver and control high-level liput voltage	DIN, FORCEOFF, FORCEON	$V_{CC} = 5 V$	2.4			v
VIL	Driver and control low-level input voltage	DIN, FORCEOFF, FORCEON				0.8	V
VI	Driver and control input voltage	DIN, FORCEOFF, FORCEON		0		5.5	V
VI	Receiver input voltage			-25		25	V
т	Operating free-air temperature		MAX3243C	0		70	°C
TA	Operating nee-an temperature		MAX3243I	-40		85	0

NOTE 3: Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 3 and Figure 6)

	PARAME	TER	TEST CONDITIONS	MIN	TYP‡	MAX	UNIT
Ц	Input leakage current	FORCEOFF, FORCEON			±0.01	±1	μΑ
		Auto-powerdown disabled	No load, FORCEOFF and FORCEON at V_{CC}		0.3	1	mA
Icc	Supply current	Powered off	No load, FORCEOFF at GND		1	10	
	Cupp., San Sin	Auto-powerdown enabled	No load, FORCEOFF at V _{CC} , FORCEON at GND, All RIN are open or grounded		1	10	μΑ

[‡] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

NOTE 3. Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.



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DRIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 3 and Figure 6)

	PARAMETER	TEST CONDITIONS	MIN	түр†	MAX	UNIT
∨он	High-level output voltage	All DOUT at R _L = 3 k Ω to GND	5	5.4		V
VOL	Low-level output voltage	All DOUT at R _L = 3 k Ω to GND	-5	-5.4		V
Vo	Output voltage (mouse driveability)	DIN1 = DIN2 = GND, DIN3 = V_{CC} , 3-k Ω to GND at DOUT3, DOUT1 = DOUT2 = 2.5 mA	±5			V
Чн	High-level input current	VI = VCC		±0.01	±1	μΑ
ЧL	Low-level input current	V _I at GND		±0.01	±1	μΑ
		$V_{CC} = 3.6 \text{ V}, \qquad V_O = 0 \text{ V}$		±35	±60	mA
los	Short-circuit output current‡	$V_{CC} = 5.5 \text{ V}, \qquad V_{O} = 0 \text{ V}$]	±35	±00	IIIA
ro	Output resistance	V_{CC} , V+, and V- = 0 V, $V_O = \pm 2 V$	300	10M		Ω
l _{off}	Output leakage current	$\overline{\text{FORCEOFF}} = \text{GND}, \qquad \text{V}_{\text{O}} = \pm 12 \text{ V}, \qquad \text{V}_{\text{CC}} = 0 \text{ to } 5.5 \text{ V}$			±25	μΑ

[†] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

[‡] Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one output should be shorted at a time.

NOTE 3. Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 3 and Figure 6)

	PARAMETER	TEST CON	DITIONS MIN TYP [†] MAX			UNIT	
	Maximum data rate	C _L = 1000 pF, One DOUT switching,	R _L = 3 kΩ, See Figure 1	250			kbit/s
t _{sk(p)}	Pulse skew§	C _L = 150 pF to 2500 pF	$R_L = 3 k\Omega$ to 7 kΩ, See Figure 2		100		ns
SR(tr)	Slew rate, transition region	V_{CC} = 3.3 V, R _L = 3 kΩ to 7 kΩ	C _L = 150 pF to 1000 pF	6		30	V/µs
SK(II)	(see Figure 1)	$R_L = 3 k\Omega$ to 7 k Ω	$C_{L} = 150 \text{ pF} \text{ to } 2500 \text{ pF}$	4		30	v/µs

[†] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

 $Pulse skew is defined as <math display="inline">|t_{PLH} - t_{PHL}|$ of each channel of the same device.

NOTE 3. Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.



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RECEIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 3 and Figure 6)

	PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT	
∨он	High-level output voltage	I _{OH} = -1 mA	V _{CC} – 0.6 V	$V_{CC} - 0.1 V$		V	
VOL	Low-level output voltage	I _{OL} = 1.6 mA			0.4	V	
1/1-	Positive-going input threshold voltage	V _{CC} = 3.3 V		1.6	2.4	V	
VIT+	Positive-going input timeshold voltage	$V_{CC} = 5 V$		1.9	2.4		
V	Negative-going input threshold voltage	V _{CC} = 3.3 V	0.6	1.1		V	
VIT-	Regative-going input theshold voltage	$V_{CC} = 5 V$	0.8	1.4		v	
V _{hys}	Input hysteresis (V _{IT+} – V _{IT} –)			0.5		V	
loff	Output leakage current (except ROUT2B)	FORCEOFF = 0 V		±0.05	±10	μΑ	
ri	Input resistance	$V_I = \pm 3 V \text{ to } \pm 25 V$	3	5	7	kΩ	

[†] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

NOTE 3. Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.

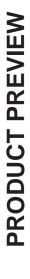
switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 3)

	PARAMETER	TEST CONDITIONS	ΜΙΝ ΤΥΡ [†] ΜΑΧ	UNIT
^t PLH	Propagation delay time, low- to high-level output	C _I = 150 pF, See Figure 3	150	ns
^t PHL	Propagation delay time, high- to low-level output	CL = 150 pr, See Figure 5	150	ns
t _{en}	Output enable time		200	ns
t _{dis}	Output disable time	$C_L = 150 \text{ pF}, R_L = 3 \text{ k}\Omega$, See Figure 4	200	ns
t _{sk(p)}	Pulse skew [‡]	See Figure 3	50	ns

[†] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

[‡] Pulse skew is defined as |tpLH – tpHL| of each channel of the same device.

NOTE 3. Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.





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AUTO-POWERDOWN SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
V _{T+(valid)}	Receiver input threshold for INVALID high-level output voltage	$\frac{\text{FORCEON} = \text{GND},}{\text{FORCEOFF}} = V_{CC}$			2.7	V
VT–(valid)	Receiver input threshold for INVALID high-level output voltage	$\frac{FORCEON}{FORCEOFF} = V_{CC}$	-2.7			V
VT(invalid)	Receiver input threshold for INVALID low-level output voltage	$\frac{FORCEON}{FORCEOFF} = V_{CC}$	-0.3		0.3	V
VOH	INVALID high-level output voltage	$I_{OH} = -1 \text{ mA}$, FORCEON = GND, FORCEOFF = V _{CC}	V _{CC} – 0.6			V
V _{OL}	INVALID low-level output voltage	$I_{OL} = 1.6 \text{ mA}$, FORCEON = GND, FORCEOFF = V_{CC}			0.4	V

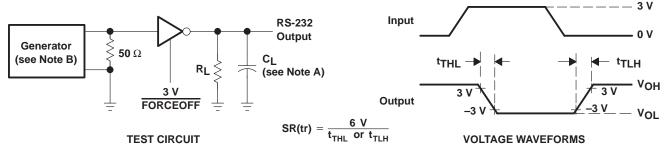
[†] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	MIN	түр†	MAX	UNIT
^t valid	Propagation delay time, low- to high-level output		1		μs
tinvalid	Propagation delay time, high- to low-level output		30		μs
t _{en}	Supply enable time		100		μs

[†] All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

PARAMETER MEASUREMENT INFORMATION



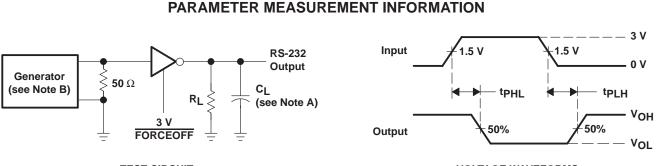
NOTES: A. CL includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_{O} = 50 \Omega$, 50% duty cycle, $t_{r} \le 10$ ns. $t_{f} \le 10$ ns.

Figure 1. Driver Slew Rate



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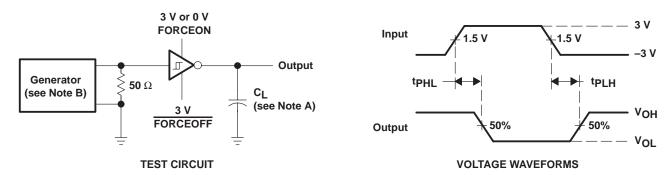




VOLTAGE WAVEFORMS

NOTES: A. Cl includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_O = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.





NOTES: A. CL includes probe and jig capacitance.

B. The pulse generator has the following characteristics: $Z_0 = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.

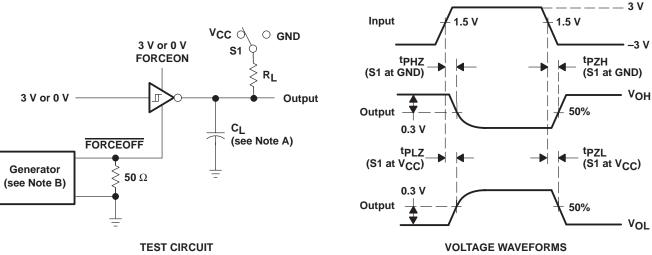


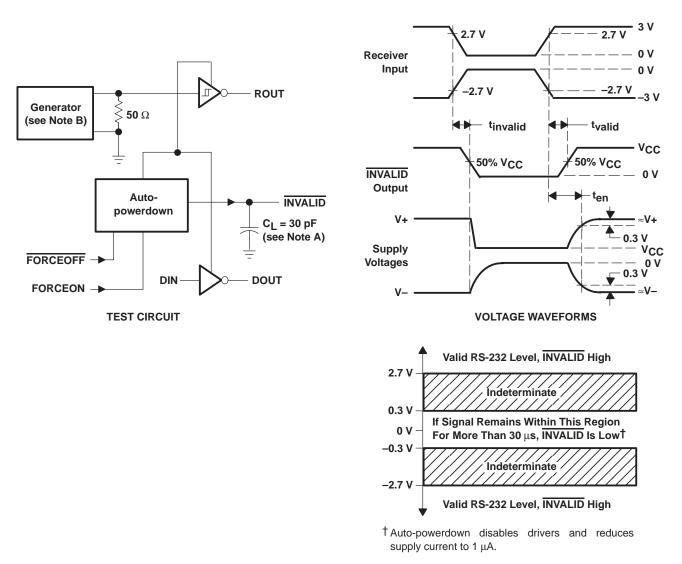
Figure 3. Receiver Propagation Delay Times

- NOTES: A. C_L includes probe and jig capacitance.
 - B. The pulse generator has the following characteristics: Z_O = 50 Ω , 50% duty cycle, t_f \leq 10 ns, t_f \leq 10 ns.
 - C. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - D. t_{PZL} and t_{PZH} are the same as t_{en} .

Figure 4. Receiver Enable and Disable Times



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PARAMETER MEASUREMENT INFORMATION

NOTES: A. C_L includes probe and jig capacitance.

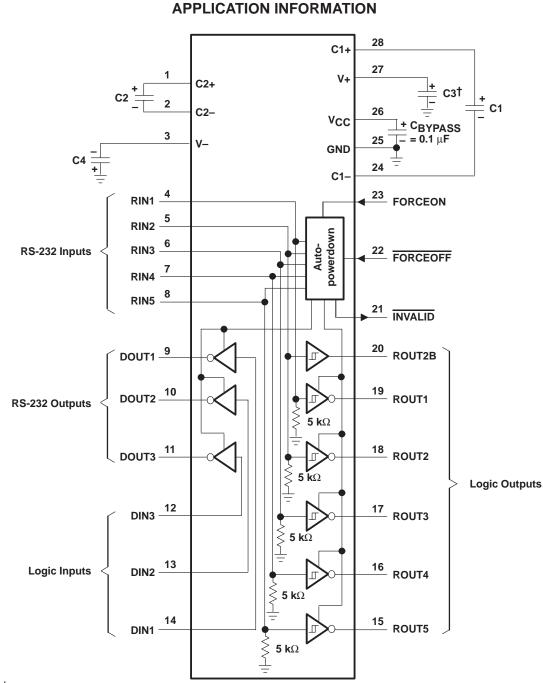
B. The pulse generator has the following characteristics: PRR = 5 kbit/s, $Z_0 = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.

Figure 5. INVALID Propagation Delay Times and Supply Enabling Time





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 $^{+}$ C3 can be connected to V_{CC} or GND. NOTE A: Resistor values shown are nominal.

V _{CC} vs (CAPACITOR	VALUES
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VCC	C1	C2, C3, and C4
$\begin{array}{c} \textbf{3.3 V} \pm \textbf{0.3 V} \\ \textbf{5 V} \pm \textbf{0.5 V} \\ \textbf{3 V to 5.5 V} \end{array}$	0.1 μF 0.047 μF 0.1 μF	0.1 μF 0.33 μF 0.47 μF

Figure 6. Typical Operating Circuit and Capacitor Values



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